

The 21st Korean Conference on Semiconductors
제21회 한국반도체학술대회
February 24–26, 2014 / Hanyang University, Seoul, Korea

J. Nano-Science & Technology 분과

[TL2-J] ReRAM

Date	Feb. 25, 2014 (Tue.)
Place	Room L / 제1공학관 503호 (# 503, Engineering Building I)

Session Chair: 김상우 교수(성균관대학교), 이택희 교수(서울대학교)

- TL2-J-1 11:10-11:40 Organic Nonvolatile Memory Devices Based on Self-Assembled Nanomaterials**
저자: Jang-Sik Lee
소속: Department of Materials Science and Engineering, Pohang University of Science and Technology
- TL2-J-2 11:40-11:55 Flexible Graphene-PZT Ferroelectric Field Effect Transistors for Nonvolatile Memory**
저자: Wonho Lee and Jong-Hyun Ahn
소속: School of Electrical & Electronic Engineering, Yonsei University
- TL2-J-3 11:55-12:10 Characterization of Nanoscale Copper-Oxide Resistive Switching Memory Devices using Self-Assembled Nano-Templates**
저자: Un-Bin Han and Jang-Sik Lee
소속: Department of Materials Science and Engineering, Pohang University of Science and Technology
- TL2-J-4 12:10-12:25 Hardware Implementation of Associative Memory Characteristics**
저자: Kibong Moon, Sangsu Park, Daeseok Lee, and Hyunsang Hwang
소속: Department of Materials Science and Engineering, Pohang University of Science and Technology